



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

SBE813

 — Low IR Schottky Barrier Diode

30V, 3.0A Rectifier

Applications

- High frequency rectification (switching regulators, converters, choppers)

Features

- Small switching noise
- Low leakage current and high reliability due to highly reliable planar structure
- Ultrasmall package permitting applied sets to be small and slim

Specifications

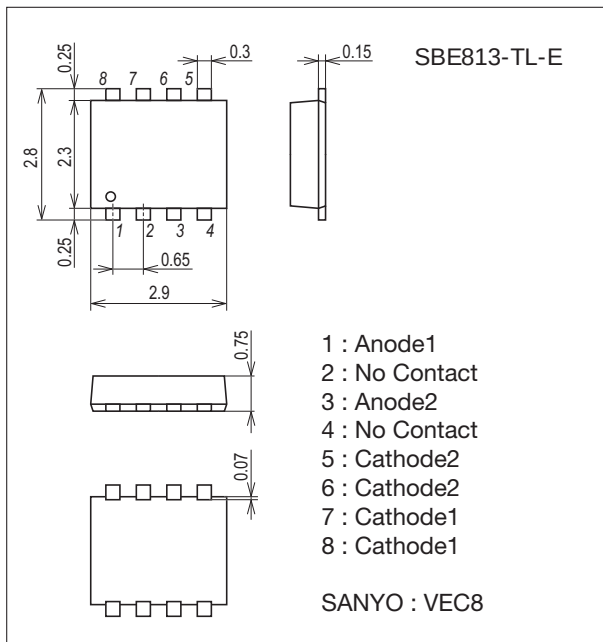
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		35	V
Average Output Current	IO		3.0	A
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	20	A
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Package Dimensions

unit : mm (typ)

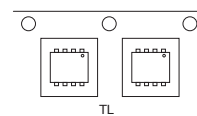
7012-001



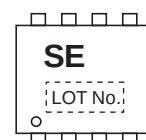
Product & Package Information

- Package : VEC8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

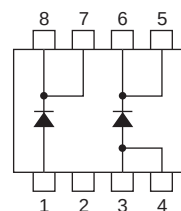
Packing Type : TL



Marking



Electrical Connection

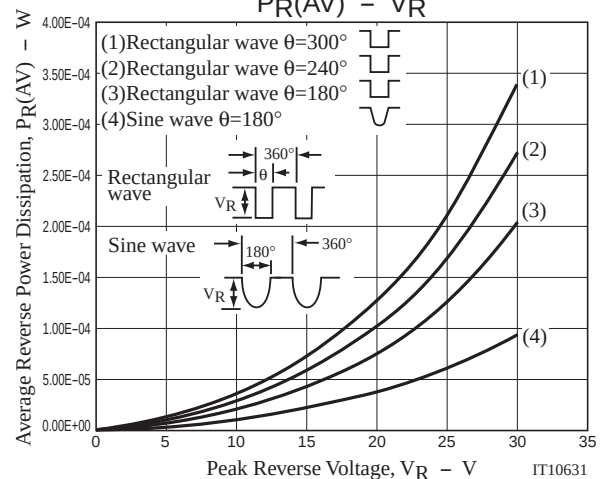
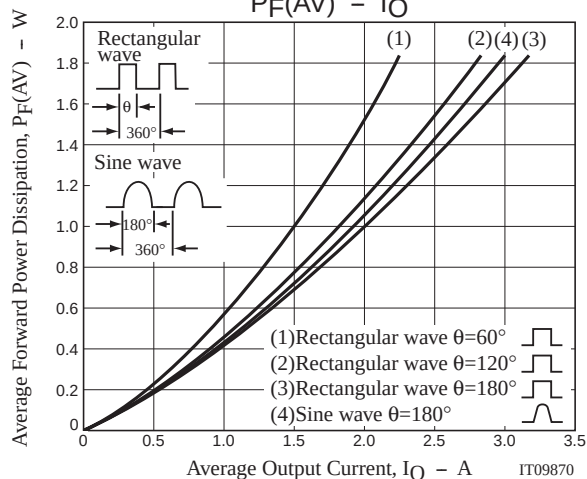
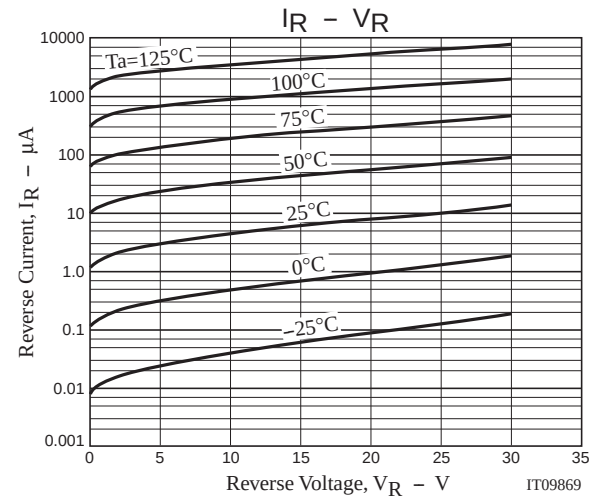
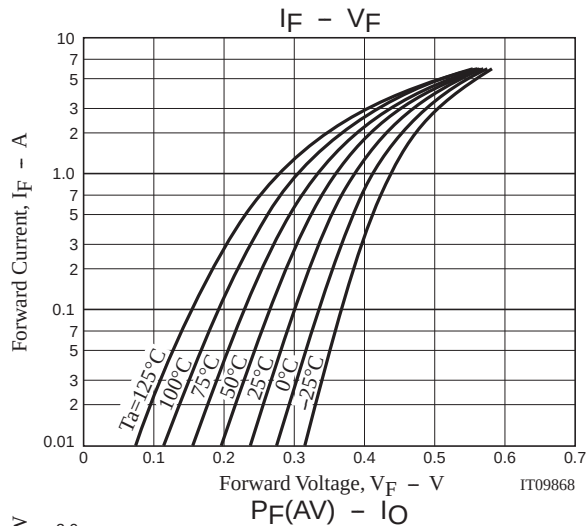


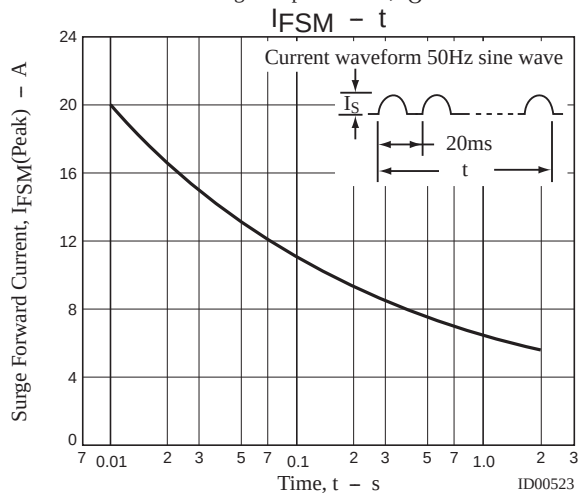
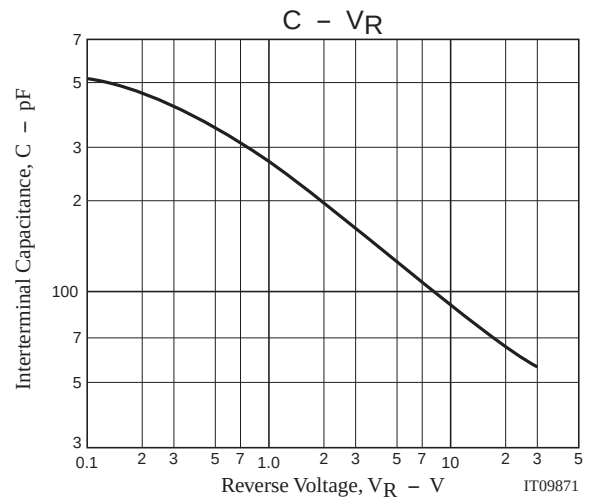
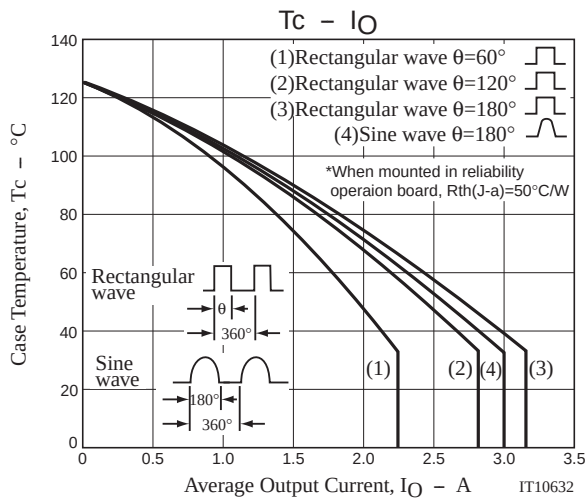
Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V_R	$I_R=0.5\text{mA}$	30			V
Forward Voltage	V_{F1}	$I_F=2.0\text{A}$		0.435	0.485	V
	V_{F2}	$I_F=3.0\text{A}$		0.47	0.52	V
Reverse Current	I_R	$V_R=15\text{V}$			42	μA
Interterminal Capacitance	C	$V_R=10\text{V}$, $f=1\text{MHz}$		90		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100\text{mA}$, See specified Test Circuit.			20	ns
Thermal Resistance	$R_{th(j-a)}$	When mounted on ceramic substrate ($1200\text{mm}^2 \times 0.8\text{mm}$)		50		$^\circ\text{C} / \text{W}$

Ordering Information

Device	Package	Shipping	memo
SBE813-TL-E	VEC8	3,000pcs./reel	Pb Free





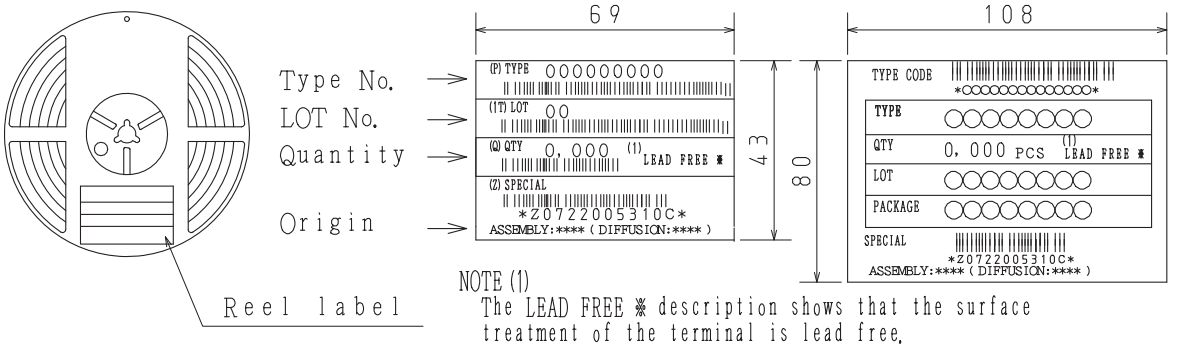
Taping Specification

SBE813-TL-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
VEC8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

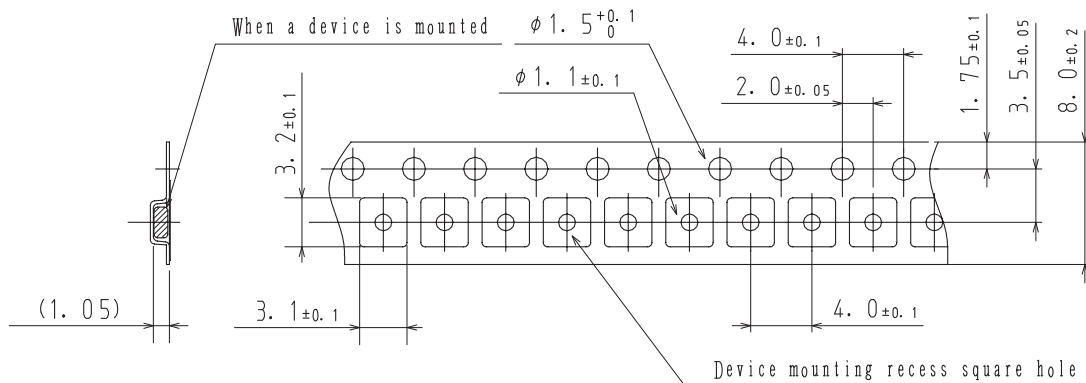
Packing method



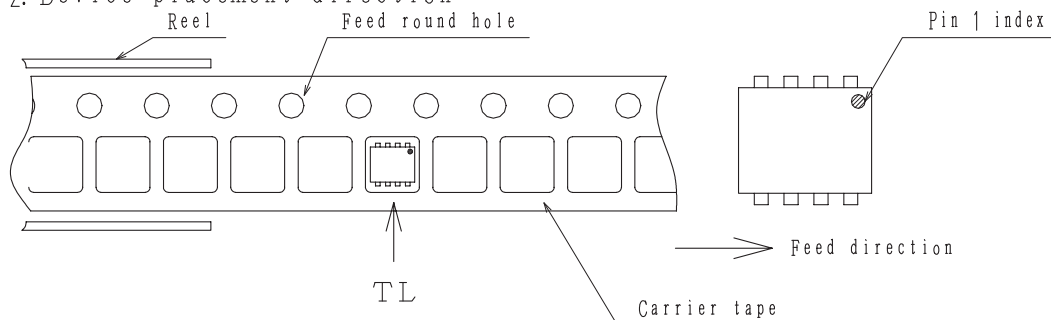
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)

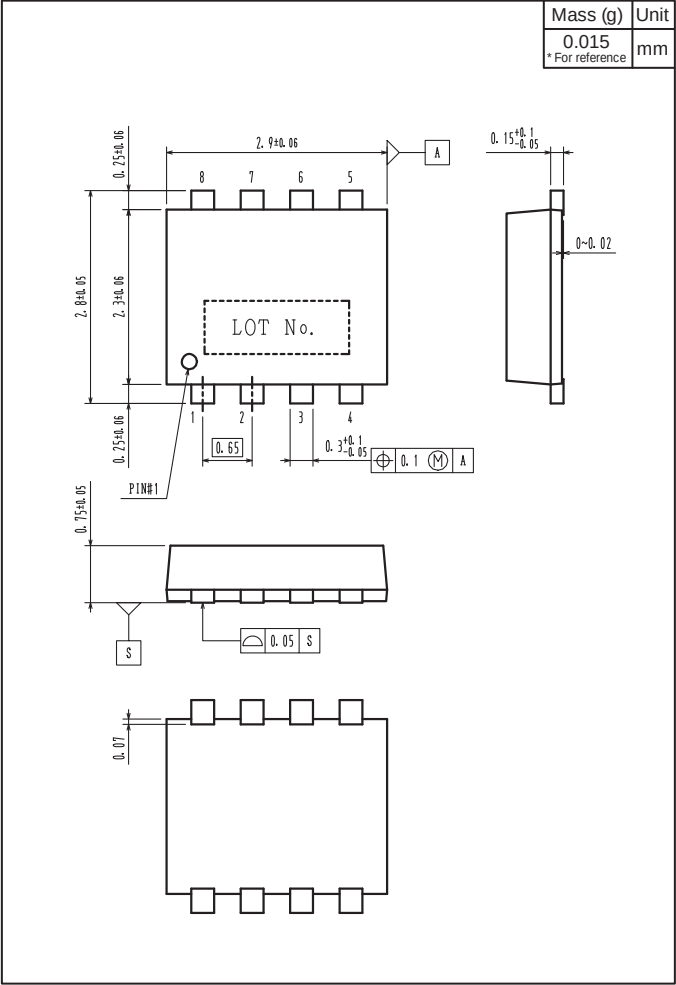


2-2. Device placement direction

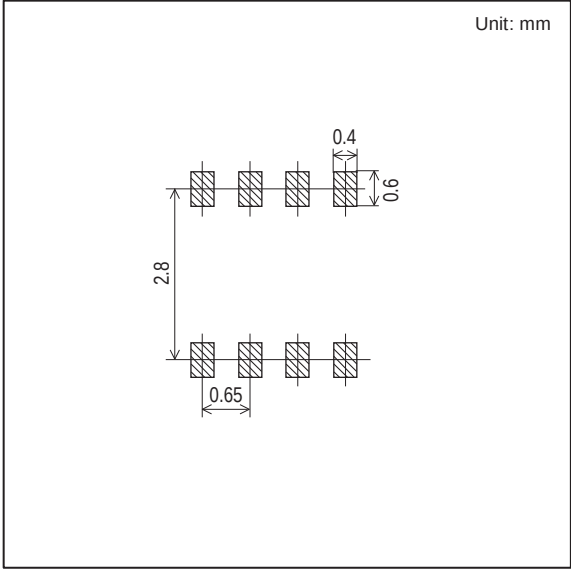


Those with oen electrode terminal on the feed hole side.....TL

Outline Drawing
SBE813-TL-E



Land Pattern Example



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